

Vishay General Semiconductor

COMPLIANT

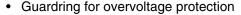
Dual Common-Cathode High-Voltage Schottky Rectifier

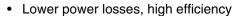
High Barrier Technology for Improved High Temperature Performance



| PRIMARY CHARACTERISTICS | | | | |
|-------------------------|-------------|--|--|--|
| $I_{F(AV)}$ | 10 A x 2 | | | |
| V_{RRM} | 90 V, 100 V | | | |
| I _{FSM} | 150 A | | | |
| V _F | 0.70 V | | | |
| I _R | 3.5 μΑ | | | |
| T _J max. | 175 °C | | | |

FEATURES





· Low forward voltage drop

Low leakage current

· High forward surge capability

· High frequency operation

Solder dip 260 °C, 40 s

 Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

MECHANICAL DATA

Case: TO-220AB

Epoxy meets UL 94V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD22-B102

E3 suffix for consumer grade, meets JESD 201 class 1A whisker test, HE3 suffix for high reliability grade (AEC Q101 qualified), meets JESD 201 class 2 whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

| MAXIMUM RATINGS (T _C = 25 °C unless otherwise noted) | | | | | |
|--|-----------------------------------|---------------|--------------|------|--|
| PARAMETER | | MBR20H90CTG | MBR20H100CTG | UNIT | |
| Maximum repetitive peak reverse voltage | V_{RRM} | 90 | 100 | V | |
| Working peak reverse voltage | V_{RWM} | 90 | 100 | V | |
| Maximum DC blocking voltage | V_{DC} | 90 | 100 | V | |
| Maximum average forward rectified current at T _C = 155 °C total device per diode | I _{F(AV)} | 20 10 | | Α | |
| Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode | I _{FSM} | 150 | | Α | |
| Peak repetitive reverse current per diode at $t_p = 2 \mu s$, 1 kHz | I _{RRM} | 0.5 | | Α | |
| Voltage rate of change (rated V _R) | dV/dt 10 000 | | V/µs | | |
| Operating junction and storage temperature range | T _J , T _{STG} | - 65 to + 175 | | °C | |

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MBR20H90CTG & MBR20H100CTG

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| ELECTRICAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | | | | |
|---|---|--|----------------|------------------------------|------------------------------|----------|--|
| PARAMETER | TEST CONDITIONS | | SYMBOL | TYP. | MAX. | UNIT | |
| Maximum instantaneous forward voltage per diode (1) | $I_F = 10 \text{ A}$ $I_F = 10 \text{ A}$ $I_F = 20 \text{ A}$ $I_F = 20 \text{ A}$ | $T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$ $T_J = 25 ^{\circ}\text{C}$ $T_J = 125 ^{\circ}\text{C}$ | V _F | 0.80 0.64 0.87 0.74 | 0.85 0.70 0.93 0.80 | ٧ | |
| Maximum reverse current per diode at working peak reverse voltage ⁽¹⁾ | | T _J = 25 °C T _J = 125 °C | I _R | - | 3.5 4.5 | μA mA | |

Note:

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

| THERMAL CHARACTERISTICS (T _C = 25 °C unless otherwise noted) | | | | |
|---|----------------|-----|------|--|
| PARAMETER | SYMBOL | MBR | UNIT | |
| Typical thermal resistance per diode | $R_{	heta JC}$ | 2.0 | °C/W | |

| ORDERING INFORMATION (Example) | | | | | | |
|--------------------------------|------------------------|-----------------|--------------|---------------|---------------|--|
| PACKAGE | PREFERRED P/N | UNIT WEIGHT (G) | PACKAGE CODE | BASE QUANTITY | DELIVERY MODE | |
| TO-220AB | MBR20H100CTG-E3/45 | 1.85 | 45 | 50/tube | Tube | |
| TO-220AB | MBR20H100CTGHE3/45 (1) | 1.85 | 45 | 50/tube | Tube | |

Note:

(1) Automotive grade AEC Q101 qualified

RATINGS AND CHARACTERISTICS CURVES

(T_A = 25 °C unless otherwise noted)

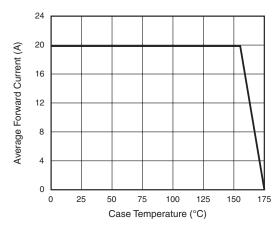


Figure 1. Forward Derating Curve

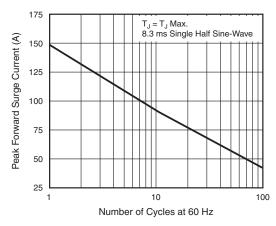


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode

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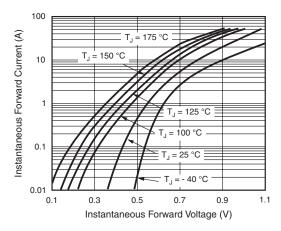


Figure 3. Typical Instantaneous Forward Characteristics Per Diode

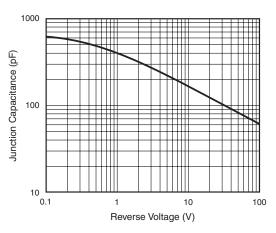


Figure 5. Typical Junction Capacitance Per Diode

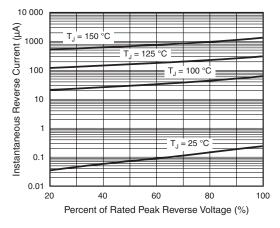


Figure 4. Typical Reverse Characteristics Per Diode

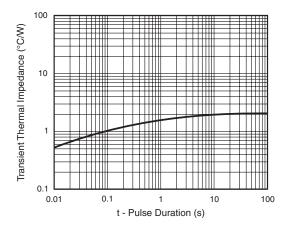
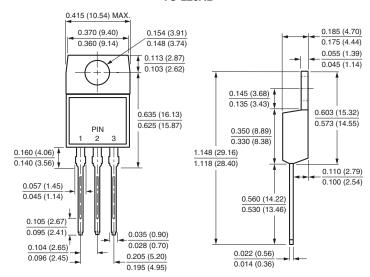


Figure 6. Typical Transient Thermal Impedance Per Diode

PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

TO-220AB



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